

### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE7080 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

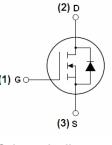
- $V_{DS} = 70V, I_D = 80A$  $R_{DS(ON)} < 8m\Omega @ V_{GS} = 10V$  (Typ:6.3m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



#### Schematic diagram



Marking and pin assignment



TO-220-3L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE7080	NCE7080	TO-220	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	70	V	
Gate-Source Voltage	VGS	±20	V	
Drain Current-Continuous	ID	80	Α	
Drain Current-Continuous(TC=100°C)	ID (100℃)	56	А	
Pulsed Drain Current	IDM	310	А	
Maximum Power Dissipation	PD	150	W	
Derating factor		1	W/℃	
Single pulse avalanche energy (Note 5)	EAS	450	mJ	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	$^{\circ}\!\mathbb{C}$	

NCE7080

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	RθJC	1	°C/W	
--	------	---	------	--

### Electrical Characteristics (T<sub>c</sub>=25°Cunless otherwise noted)

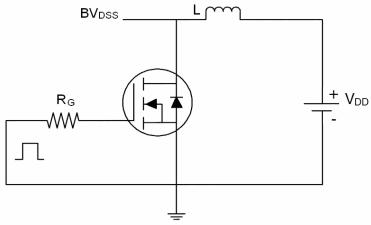
Parameter	Parameter Symbol Condition		Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BVDSS	VGS=0V ID=250µA	70	74	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=70V,VGS=0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250μA	2	3	4	V
Drain-Source On-State Resistance	RDS(ON)	VGS=10V, ID=30A	-	6.3	8	mΩ
Forward Transconductance	gFS	VDS=25V,ID=30A	50	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	Clss	\/DC-25\/\/CC-0\/	-	3400	-	PF
Output Capacitance	Coss	VDS=25V,VGS=0V,	-	310	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	221	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	td(on)		-	15	-	nS
Turn-on Rise Time	tr	VDD=30V,ID=2A,RL=15Ω	-	11	-	nS
Turn-Off Delay Time	td(off)	VGS=10V,RG=2.5Ω	-	52	-	nS
Turn-Off Fall Time	tf		-	13	-	nS
Total Gate Charge	Qg	VDC 20V ID 20A	-	94	-	nC
Gate-Source Charge	Qgs	VDS=30V,ID=30A, VGS=10V	-	16	-	nC
Gate-Drain Charge	Qgd	VGS=10V	-	24	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	VSD	VGS=0V,IS=30A	-	-	1.2	V
Diode Forward Current (Note 2)	IS		-	-	78	Α
Reverse Recovery Time	trr	TJ = 25°C, IF =75A	-	33		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs <sup>(Note3)</sup>	-	54		nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LI				y LS+LD)
		•				

#### Notes:

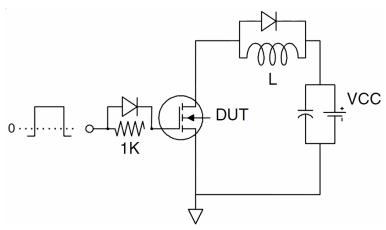
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25  $^{\circ}\text{C}, V_{DD}\text{=}35\text{V}, V_{G}\text{=}10\text{V}, L\text{=}0.5\text{mH}, Rg\text{=}25\Omega$

## **Test Circuit**

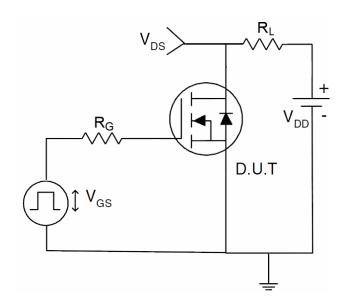
# 1) EAS test Circuit



# 2) Gate charge test Circuit

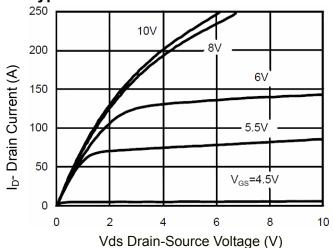


# 3) Switch Time Test Circuit

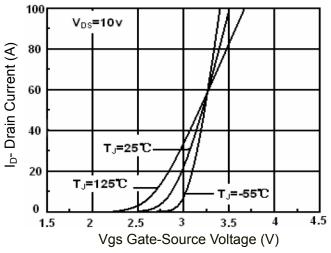




### **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

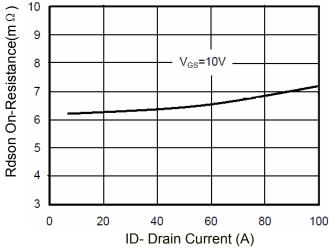


Figure 3 Rdson- Drain Current

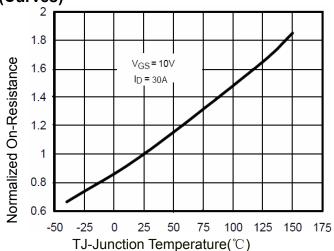


Figure 4 Rdson-JunctionTemperature

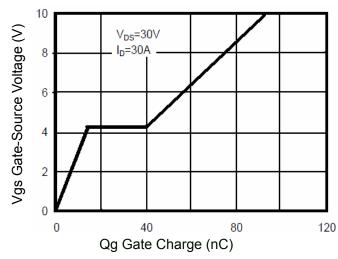


Figure 5 Gate Charge

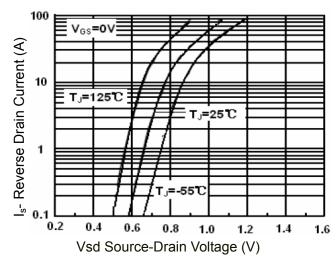


Figure 6 Source- Drain Diode Forward

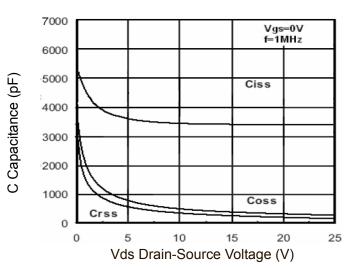


Figure 7 Capacitance vs Vds

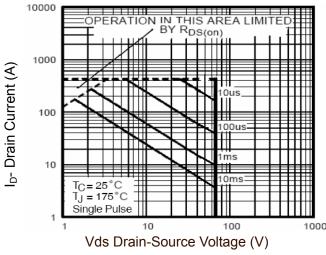


Figure 8 Safe Operation Area

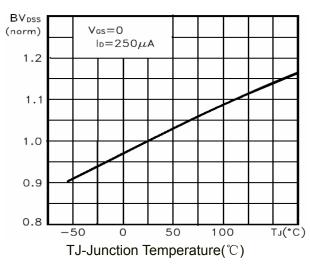


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

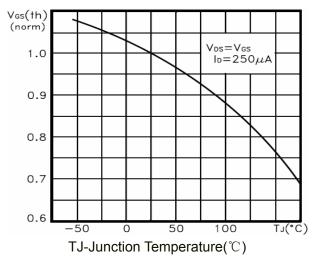
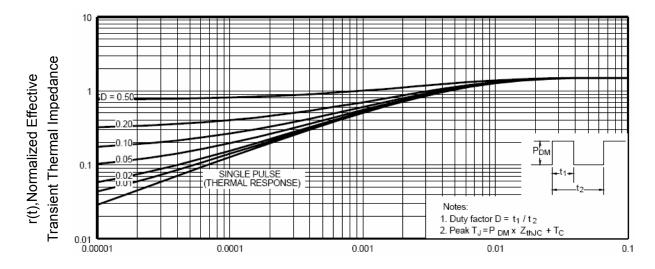


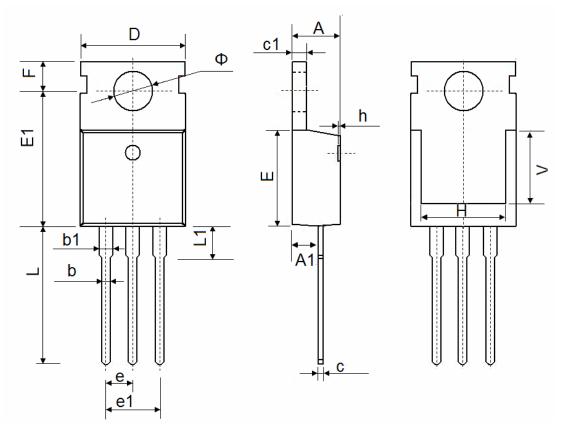
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-220-3L Package Information**



Complete	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	TYP.	0.100	0.100 TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500	0 REF. 0.295 REF.		REF.	
Ф	3.400	3.800	0.134	0.150	

#### http://www.ncepower.com

NCE7080

### Attention:

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.